NSN 5962-01-368-3227

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View Online at https://aerobasegroup.com/nsn/5962-01-368-3227

Body Length:

Between 1.065 inches and 1.085 inches

Body Width:

Between 0.390 inches and 0.420 inches

Body Height:

Between 0.040 inches and 0.125 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

W/disable and low current and 3-state output and high speed and hermetically sealed and high impedance

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

16 input

Current Rating Per Characteristic:

5.00 milliamperes reverse current, dc microamperes

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

7.50 input picofarads and 15.00 output picofarads

Time Rating Per Chacteristic:

350.00 nanoseconds access

Memory Device Type:

Ram

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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